

High power NPN epitaxial planar bipolar transistor

Features

- High breakdown voltage $V_{CE0} = 230\text{ V}$
- Complementary to 2STA1962
- Fast-switching speed
- Typical $f_T = 30\text{ MHz}$

Application

- Audio power amplifier

Description

This device is a NPN transistor manufactured using new BiT-LA (Bipolar Transistor for linear amplifier) technology. The resulting transistor shows good gain linearity behaviour.

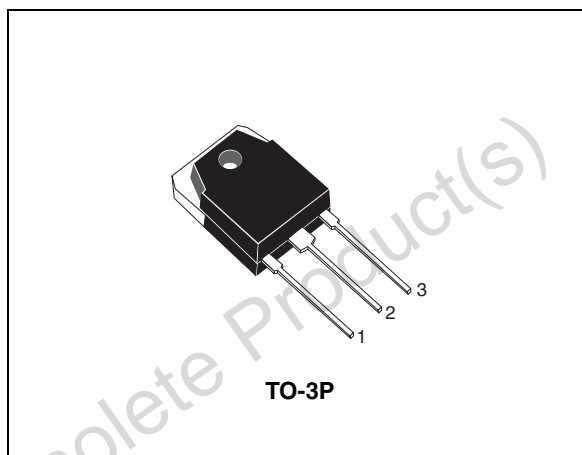


Figure 1. Internal schematic diagram

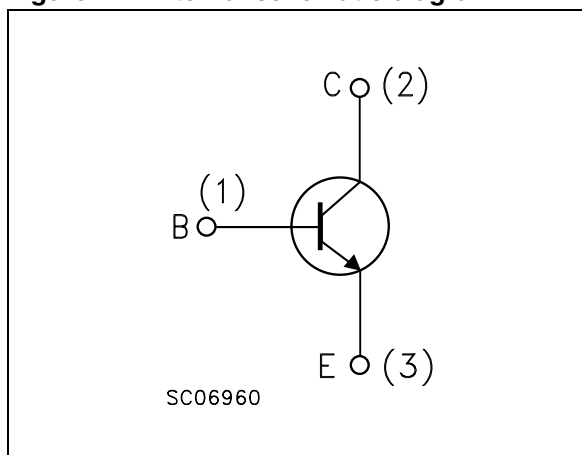


Table 1. Device summary

Order code	Marking	Package	Packaging
2STC5242	2STC5242	TO-3P	Tube

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-base voltage ($I_E = 0$)	230	V
V_{CEO}	Collector-emitter voltage ($I_B = 0$)	230	V
V_{EBO}	Emitter-base voltage ($I_C = 0$)	5	V
I_C	Collector current	15	A
I_{CM}	Collector peak current	30	A
P_{tot}	Total dissipation at $T_C = 25^\circ\text{C}$	150	W
T_{stg}	Storage temperature	-55 to 150	$^\circ\text{C}$
T_J	Operating junction temperature	150	$^\circ\text{C}$

Table 3. Thermal data

Symbol	Parameter	Value	Unit
$R_{thJ-case}$	Thermal resistance junction-case Max	0.83	$^\circ\text{C}/\text{W}$

2 Electrical characteristics

($T_{\text{case}} = 25\text{ °C}$ unless otherwise specified)

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{CBO}	Collector cut-off current ($I_{\text{E}} = 0$)	$V_{\text{CB}} = 230\text{ V}$			5	μA
I_{EBO}	Emitter cut-off current ($I_{\text{C}} = 0$)	$V_{\text{EB}} = 5\text{ V}$			5	μA
$V_{(\text{BR})\text{CEO}}^{(1)}$	Collector-emitter breakdown voltage ($I_{\text{B}} = 0$)	$I_{\text{C}} = 50\text{ mA}$	230			V
$V_{(\text{BR})\text{CBO}}$	Collector-base breakdown voltage ($I_{\text{E}} = 0$)	$I_{\text{C}} = 100\text{ }\mu\text{A}$	230			V
$V_{(\text{BR})\text{EBO}}^{(1)}$	Emitter-base breakdown voltage ($I_{\text{C}} = 0$)	$I_{\text{E}} = 1\text{ mA}$	5			V
$V_{\text{CE(sat)}}^{(1)}$	Collector-emitter saturation voltage	$I_{\text{C}} = 8\text{ A}$ $I_{\text{B}} = 800\text{ mA}$			3	V
V_{BE}	Base-emitter voltage	$I_{\text{C}} = 7\text{ A}$ $V_{\text{CE}} = 5\text{ V}$			1.5	V
h_{FE}	DC current gain	$I_{\text{C}} = 1\text{ A}$ $V_{\text{CE}} = 5\text{ V}$ $I_{\text{C}} = 7\text{ A}$ $V_{\text{CE}} = 5\text{ V}$	80 35		160	
t_{on} t_{s} t_{f}	Resistive load Turn-on time Storage time Fall time	$V_{\text{CC}} = 60\text{ V}$ $I_{\text{C}} = 5\text{ A}$ $I_{\text{B1}} = -I_{\text{B2}} = 0.5\text{ A}$		0.24 4.7 0.6		μs μs μs
f_{T}	Transition frequency	$I_{\text{C}} = 1\text{ A}$ $V_{\text{CE}} = 5\text{ V}$		30		MHz
C_{CBO}	Collector-base capacitance ($I_{\text{E}} = 0$)	$V_{\text{CB}} = 10\text{ V}$ $f = 1\text{ MHz}$		150		pF

1. Pulsed: pulse duration = 300 μs , duty cycle $\leq 1.5\%$

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

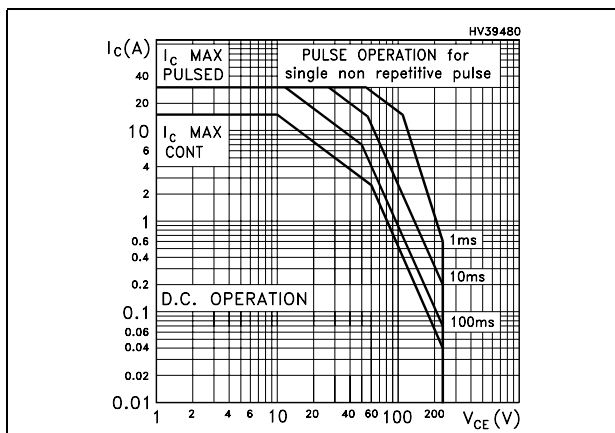


Figure 3. Derating curve

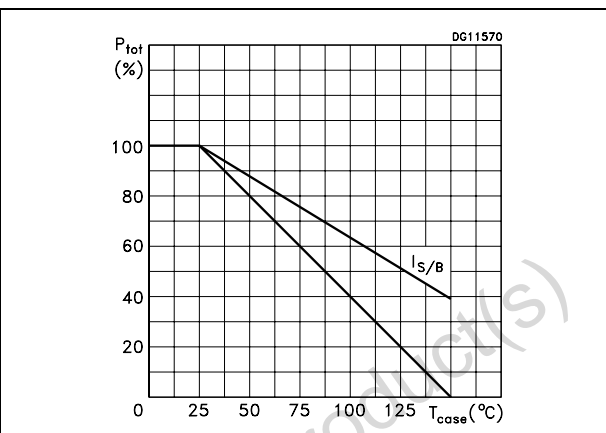


Figure 4. Output characteristics

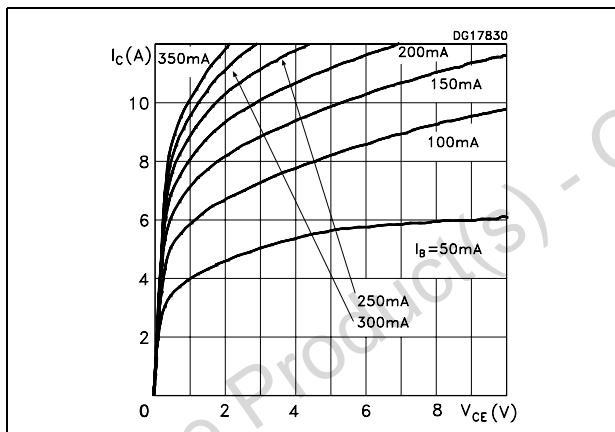


Figure 5. DC current gain

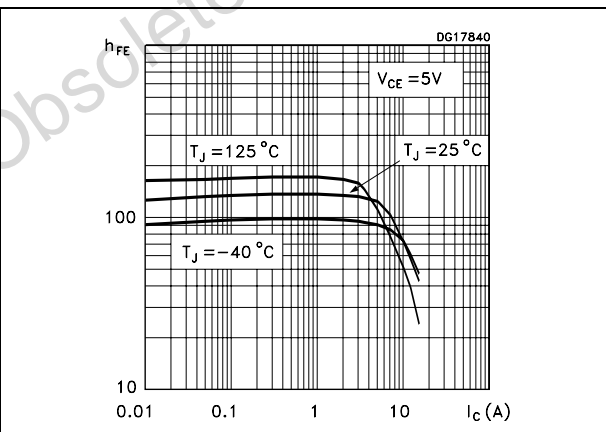


Figure 6. Collector-emitter saturation voltage

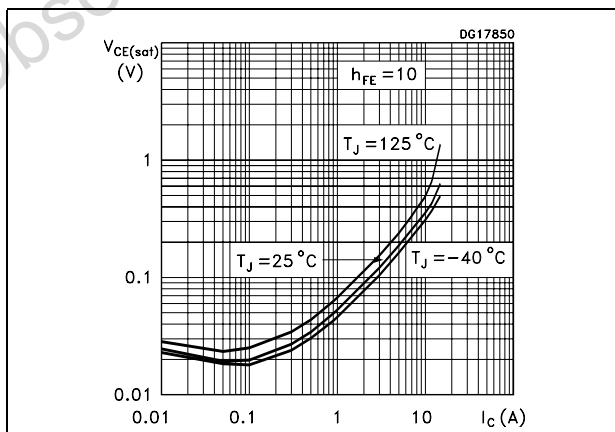
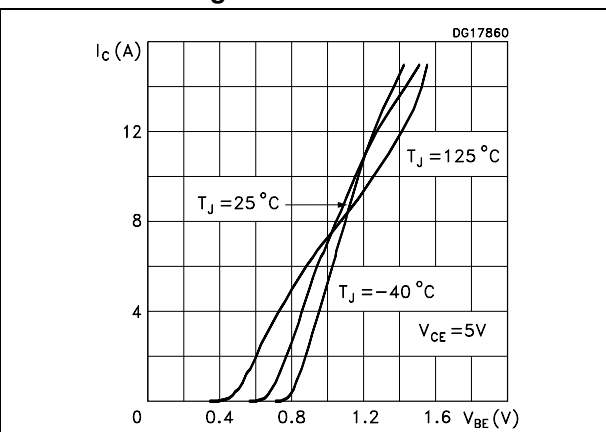
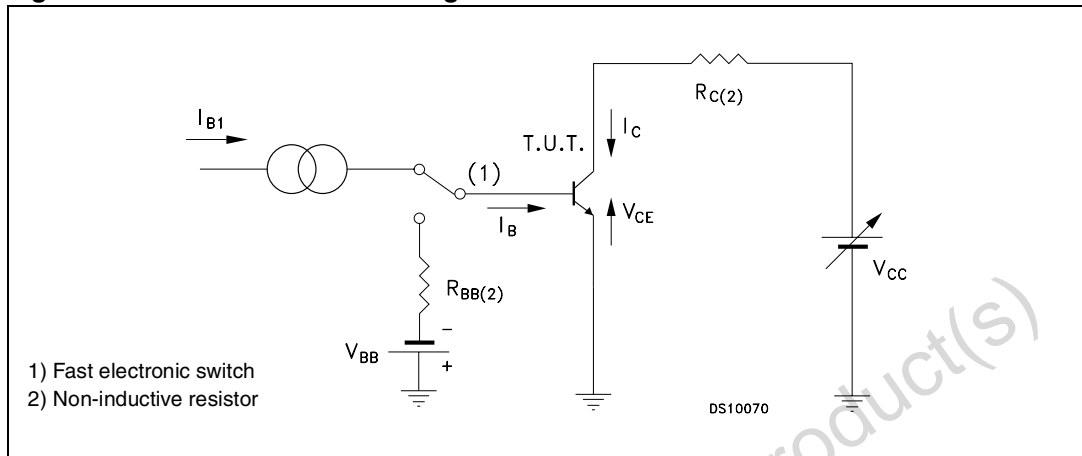


Figure 7. Collector current vs base-emitter voltage



2.2 Test circuit

Figure 8. Resistive load switching test circuit



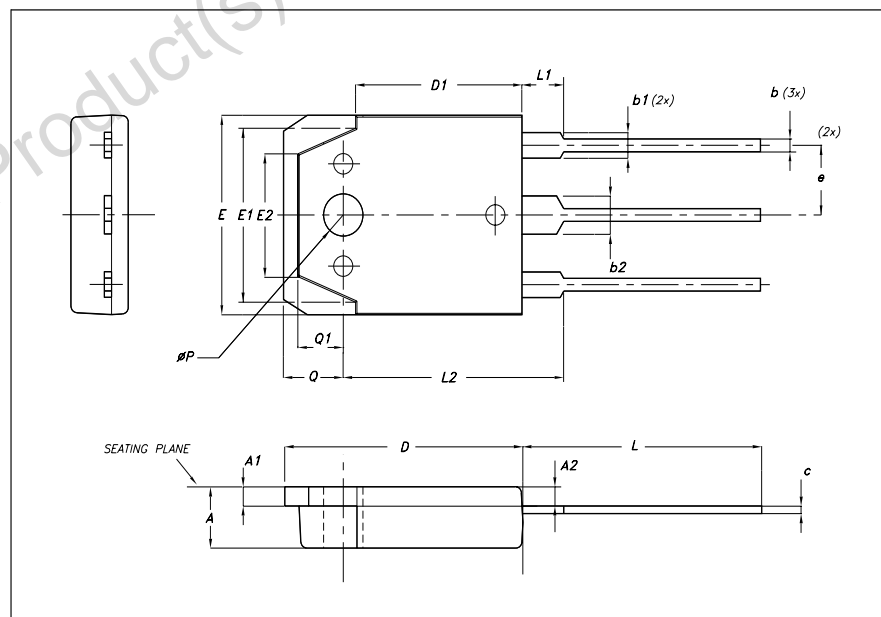
3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

Obsolete Product(s) - Obsolete Product(s)

TO-3P Mechanical data

DIM.	mm.		
	MIN.	TYP	MAX.
A	4.6		5
A1	1.45	1.50	1.65
A2	1.20	1.40	1.60
b	0.80	1	1.20
b1	1.80		2.20
b2	2.80		3.20
c	0.55	0.60	0.75
D	19.70	19.90	20.10
D1		13.90	
E	15.40		15.80
E1		13.60	
E2		9.60	
e	5.15	5.45	5.75
L	19.50	20	20.50
L1		3.50	
L2	18.20	18.40	18.60
P	3.10		3.30
Q		5	
Q1		3.80	



4 Revision history

Table 5. Document revision history

Date	Revision	Changes
28-Sep-2007	1	Initial release.
11-Dec-2007	2	Document promoted from preliminary data to datasheet.
14-Jul-2008	3	Updated total power dissipation and relevant thermal resistance junction-case value.

Obsolete Product(s) - Obsolete Product(s)

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